10W GaAs pHEMT SPDT SWITCH

Package: 3mmx3mm QFN



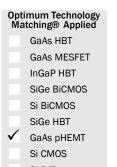
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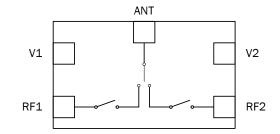
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Product Description

The FMS2031-001 is a 10W, Single-pole, Double-throw, (SPDT) GaAs pHEMT reflective antenna switch. The switch offers excellent power handling capability and harmonic performance. The FMS2031-001 is designed for use in WiMax, L-, S-, and Cband wireless applications and WLAN access points where high linearity switching is required.



- Si BJT
- GaN HEMT
- InP HBT
- RF MEMS
- LDMOS



Features

- 31dB Isolation at 2.5GHz
- 0.5dB Insertion Loss at 2.5GHz
- P_{0.1dB} 41dBm at 2.3GHz
- Less than 10µA Control Current at 35dBm Input Power

Applications

- WiMax
- L-, S-, and C-band Applications
- WLAN Applications

Parameter	Specification			Unit	Condition	
Farameter	Min. Typ.		Max.	Unit	Condition	
Electrical Specifications					$T_{AMBIENT}$ =25 °C, V_{CTRL} =0V/2.7V, Z_{IN} = Z_{OUT} =50 Ω	
Insertion Loss		0.5	0.7	dB	DC to 3GHz	
		1		dB	3GHz to 4GHz	
		0.9		dB	4 GHz to 5 GHz	
Return Loss		20		dB	DC to 4GHz	
		15		dB	4 GHz to 5 GHz	
		10		dB	4.9GHz to 5.9GHz	
Isolation	30	32		dB	DC to 3GHz	
		29		dB	3GHz to 4GHz	
		23		dB	4GHz to 5GHz	
P _{IN} at 0.1dB Compression Point		43		dBm	900MHz	
		41		dBm	2.3GHz	
2nd Harmonic		-83		dBc	900MHz, 35dBm CW	
		-85	-73	dBc	1950MHz, 33dBm CW	
3rd Harmonic		-85		dBc	900MHz, 35dBm CW	
		-81	-73	dBc	1950MHz, 33dBm CW	
EVM (Contribution Due to Switch)		∆0.5		%	35dBm at 5.9GHz (OFDM WLAN 54)	
IIP3		60		dBm	1950MHz, 1MHz spacing, +20dBm per tone	
IIP2		87		dBm	1950MHz, 1MHz spacing, +20dBm per tone	
Switching Speed: T _{RISE} , T _{FALL}		90		ns	10% to 90% RF and 90% to 10% RF	
Switching Speed: T _{ON} , T _{OFF}		350		ns	50% control to 10% and 90% RF	
Control Current		<5	10	μΑ	+35dBm RF input @ 0.96GHz	

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Absolute Maximum Ratings

g Unit
dBm
dBm
A
V
5 °C
°C
50 °C

Notes:

At high powers, the dissipation in the switch can be significant and the resulting thermal effects need to be taken into account. The device should be appropriately heat-sinked.

For thermal calculations, the dissipation within the switch should be taken as η = 5.5%. This should include the power input to the switch and reflected back from an external mismatch.

The thermal resistance of the switch is R_{TH} = 70 °C/W.

 $T_J = T_{OP} + P_{IN} \cdot \eta$. R_{TH} , where $T_J < T_{JMAX}$

Disclaimer

This product is not designed for use in any space-based or life-sustaining/supporting equipment.

Truth Table

Switch State	VC1	VC2	ANT - RF1	ANT - RF2
А	High	Low	Insertion loss	Isolation
В	Low	High	Isolation	Insertion Loss

Note: External DC blocking capacitors are required on all RF ports. All unused ports terminated in 50Ω.

High: +2.3V to +6V. Low: +0V to +0.2V.

Ordering Information

Delivery Quantity	Ordering Code
Reel of 1000	FMS2031-001
Reel of 100	FMS2031-001SR
Bag of 25	FMS2031-001SQ
Bag of 5	FMS2031-001SB
Evaluation Board	FMS2031-001-PCK1



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

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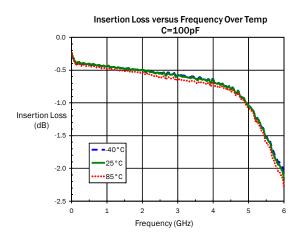
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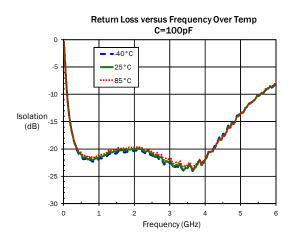
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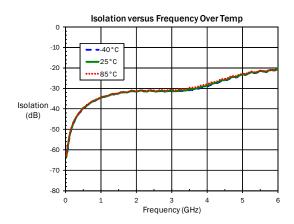


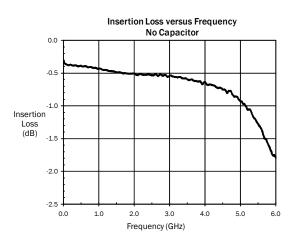
Typical Measured Performance on Evaluation Board (De-embedded)

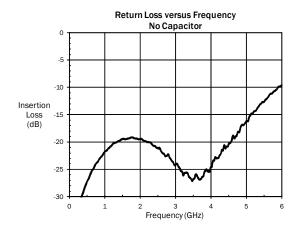
Measurement Conditions: V_{CTRL}=2.7V (high) and OV (low), T_{AMBIENT}=25 °C unless otherwise stated.

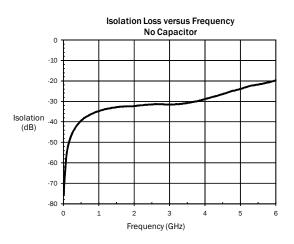








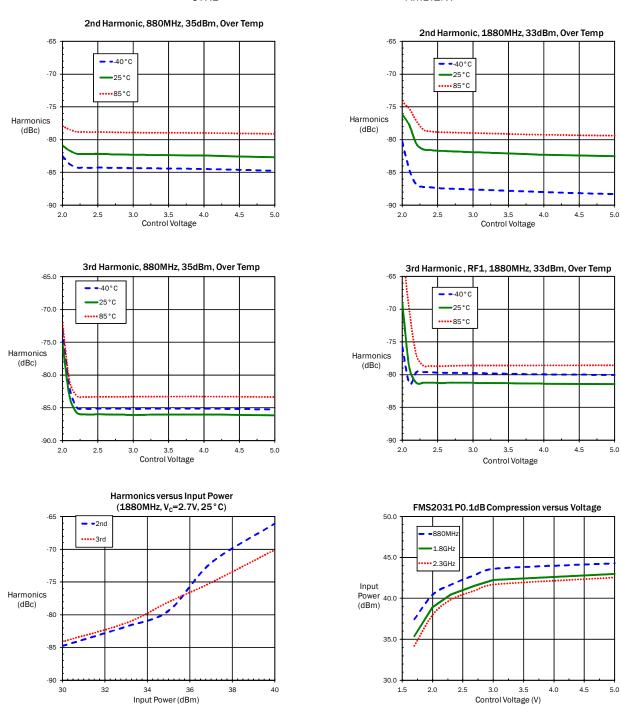






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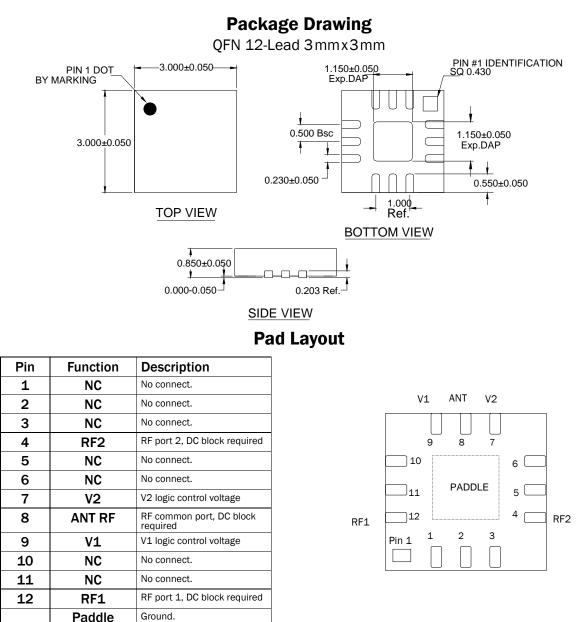




Part Identification



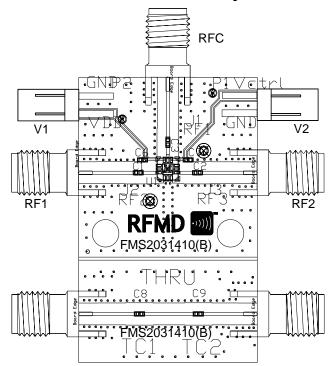
First row: Device code "2031". Second row: Trace Code, to be assigned by SubCon.



Tape and Reel Specification

Tape and reel information on this material is in accordance with EIA-481-1 except where exceptions are identified.





Evaluation Board Layout

Bill of Materials

Label	Component
C1-C9	Capacitor, 100 pF, 0402